



Photocoupler Product Data Sheet 4N35/ 4N37 (M, S, S-TA1)

Spec No. :DS-70-99-0012
Effective Date: 08/22/2017
Revision: E

LITE-ON DCC


RELEASE

BNS-OD-FC001/A4

Photocoupler 4N3X series

1. DESCRIPTION

1.1 Features

- Current transfer ratio (CTR : MIN. 100% at $I_F = 10\text{mA}$, $V_{CE} = 10\text{V}$, $T_a = 25^\circ\text{C}$)
- High input-output isolation voltage
4N35 series : $V_{iso} = 3,550\text{Vrms}$
4N37 series : $V_{iso} = 1,500\text{Vrms}$
- Response time (t_r : TYP. $3\mu\text{s}$ at $V_{CC} = 10\text{V}$, $I_C = 2\text{mA}$, $R_L = 100\Omega$)
- Dual-in-line package :
4N35, 4N37
- Wide lead spacing package :
4N35M, 4N37M
- Surface mounting package :
4N35S, 4N37S
- Tape and reel packaging :
4N35S-TA, 4N37S-TA, 4N35S-TA1, 4N37S-TA1
- Safety approval
* UL approved (No. E113898)
* CSA approved (No. CA91533-1)
* FIMKO approved (No. 193422-01)
* VDE approved (No. 40015248)
* BSI approved (No. 9018-9)
* CQC approved (No.CQC11001061921-2)
- Creepage distance > 8.0 mm ; Clearance > 8.0 mm
- The relevant models are the models Approved by VDE according to DIN EN 60747-5-5
Approved Model No.: 4N35-V / 4N37-V / 4N35M-V / 4N37M-V / 4N35S-V / 4N37S-V / 4N35STA-V / 4N37STA-V /
4N35STA1-V / 4N37STA1-V
VDE approved No.: 40015248 (According to the specification DIN EN 60747-5-5)
- Operating isolation voltage V_{IORM} : 420V (Peak)
- Transient voltage V_{TR} : 6000V (Peak)
- Pollution : 2 (According to VDE 0110-1 : 1997-04)
- Clearances distance (Between input and output) : 7.0mm (MIN.)
- Creepage distance (Between input and output) : 7.0mm (MIN.)
- Isolation thickness between input and output : 0.4mm (MIN.)
- Safety limit values Current (I_{si}) : 400mA (Diode side)
Power (P_{si}) : 700mW (Phototransistor side)
Temperature(T_{si}) : 175°C
In order to keep safety electric isolation of photocoupler, please set the protective circuit to keep within safety limit values when the actual application equipment troubled.
- Indication of VDE approval prints "" on sleeve package.

Photocoupler 4N3X series

- RoHS Compliance
All materials be used in device are followed EU RoHS directive (No.2002/95/EC).
- ESD pass HBM 8000V/MM2000V
- MSL class1

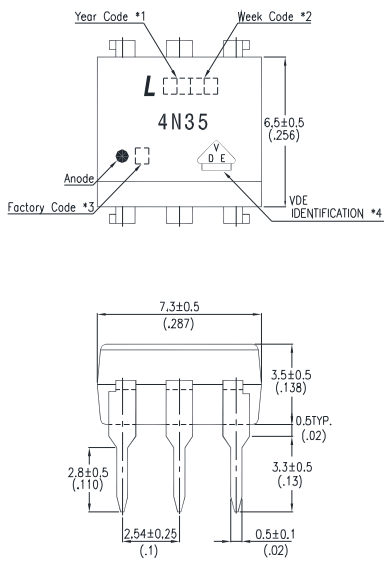
1.2 Applications

- Power Supply regulators
- Digital logic inputs
- Microprocessor inputs

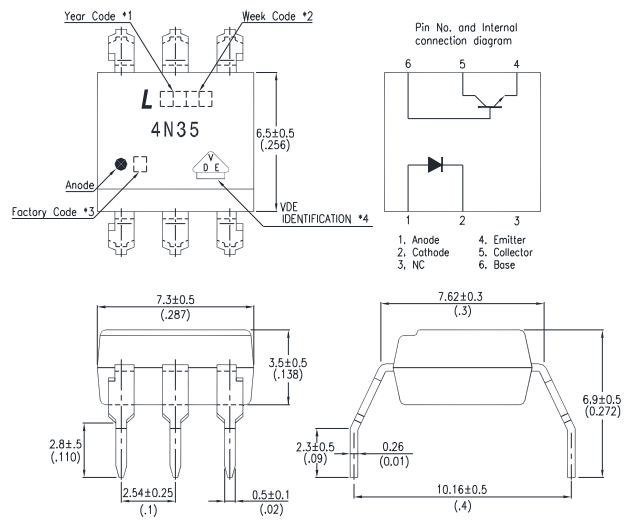
Photocoupler 4N3X series

2. PACKAGE DIMENSIONS

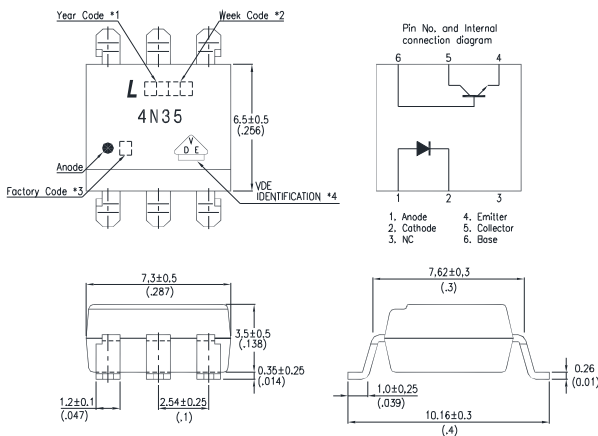
2.1 4N35



2.2 4N35M



2.3 4N35S



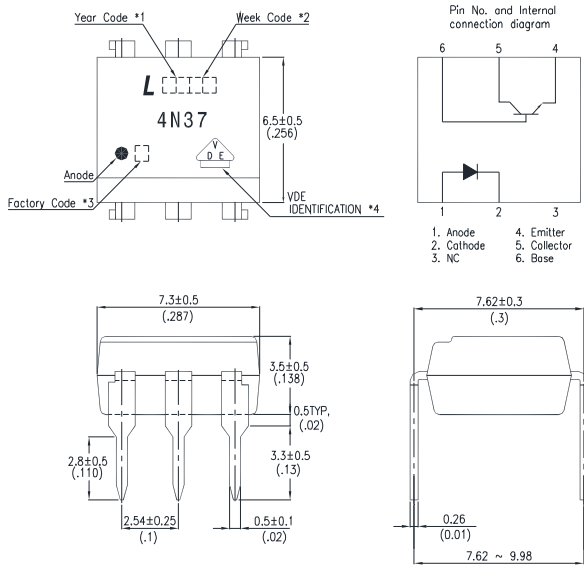
Notes :

1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (W: China-CZ, Y: Thailand X: China-TJ).
4. VDE option.

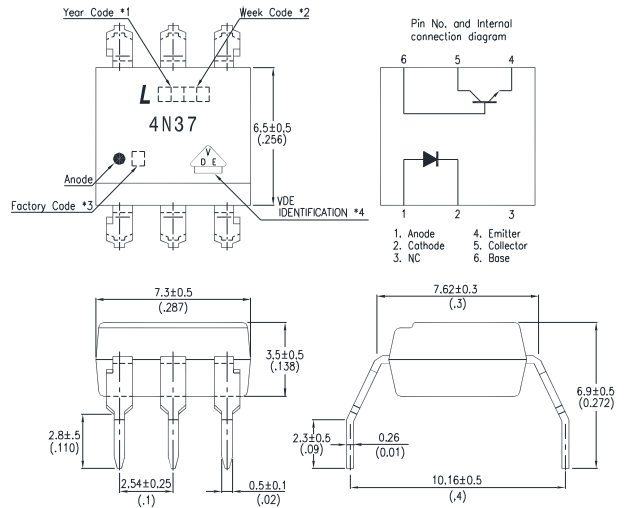
Dimensions in millimeters(inches).

Photocoupler 4N3X series

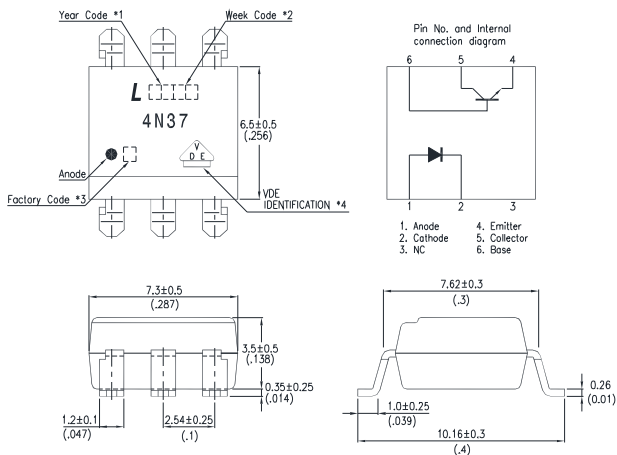
2.4 4N37



2.5 4N37M



2.6 4N37S



Notes :

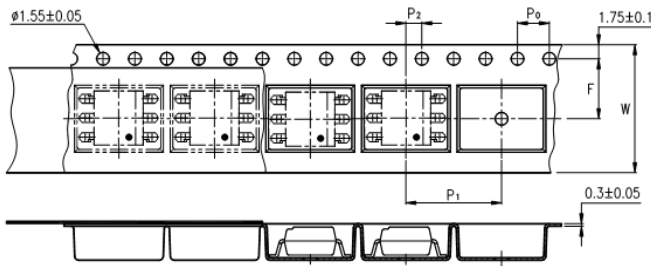
1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (W: China-CZ, Y: Thailand X: China-TJ).
4. VDE option.

Dimensions in millimeters(inches).

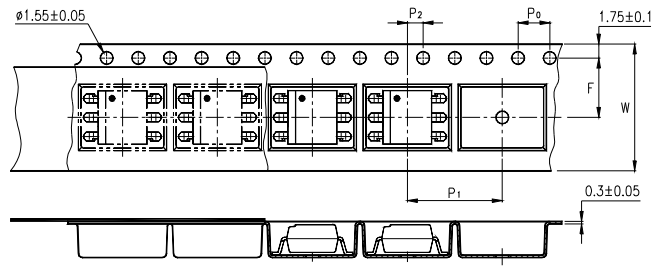
**Photocoupler
4N3X series**

3. TAPING DIMENSIONS

3.1 4N35S-TA, 4N37S-TA :



3.2 4N35S-TA1, 4N37S-TA1 :



| Description | Symbol | Dimension in mm (inch) |
|--|----------------|------------------------|
| Tape wide | W | 16±0.3 (0.63) |
| Pitch of sprocket holes | P ₀ | 4±0.1 (0.15) |
| Distance of compartment | F | 7.5±0.1 (0.295) |
| | P ₂ | 2±0.1 (0.079) |
| Distance of compartment to compartment | P ₁ | 12±0.1 (0.472) |

3.3 Quantities Per Reel

| Package Type | TA/TA1 |
|------------------|--------|
| Quantities (pcs) | 1000 |

Photocoupler 4N3X series

4. RATING AND CHARACTERISTICS

4.1 Absolute Maximum Ratings at Ta=25°C

| Parameter | | Symbol | Rating | Unit |
|--------------------------|-----------------------------|-----------|------------|-----------|
| Input | Forward Current | I_F | 60 | mA |
| | Reverse Voltage | V_R | 6 | V |
| | Power Dissipation | P | 100 | mW |
| Output | Collector - Emitter Voltage | V_{CEO} | 30 | V |
| | Emitter - Collector Voltage | V_{ECO} | 7 | V |
| | Collector - Base Voltage | V_{CBO} | 70 | V |
| | Collector Current | I_C | 100 | mA |
| | Collector Power Dissipation | P_C | 300 | mW |
| Total Power Dissipation | | P_{tot} | 350 | mW |
| *1 Isolation Voltage | 4N35 series | V_{iso} | 3,550 | V_{rms} |
| | 4N37 series | | 1,500 | V_{rms} |
| Operating Temperature | | T_{opr} | -55 ~ +100 | °C |
| Storage Temperature | | T_{stg} | -55 ~ +150 | °C |
| *2 Soldering Temperature | | T_{sol} | 260 | °C |

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

- (1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.
- (2) The isolation voltage tester with zero-cross circuit shall be used.
- (3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

Photocoupler 4N3X series

4.2 ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

| PARAMETER | | SYMBOL | MIN. | TYP. | MAX. | UNIT | CONDITIONS |
|-----------------------------|---|----------|--------------------|--------------------|------|------|---------------------------|
| INPUT | Forward Voltage | VF | — | 1.2 | 1.5 | V | IF=10mA |
| | Reverse Current | IR | — | — | 10 | μA | VR=4V |
| | Terminal Capacitance | Ct | — | 50 | — | pF | V=0, f=1KHz |
| OUTPUT | Collector Dark Current | ICEO | — | — | 50 | nA | VCE=10V, IF=0 Ta=25°C |
| | | | — | — | 500 | μA | VCE=30V, IF=0 Ta=100°C |
| | Collector-Emitter Breakdown Voltage | BVCEO | 30 | — | — | V | IC=0.1mA IF=0 |
| | Emitter-Collector Breakdown Voltage | BVECO | 7 | — | — | V | IE=10μA IF=0 |
| | Collector-Base Breakdown Voltage | BVCBO | 70 | — | — | V | IC=0.1mA IF=0 |
| TRANSFER CHARACTERISTICS | Collector Current | IC | 10 | — | — | mA | IF=10mA |
| | *Current Transfer Ratio | CTR | 100 | — | — | % | VCE=10V |
| | Collector-Emitter Saturation Voltage | VCE(sat) | — | — | 0.3 | V | IF=50mA IC=2mA |
| | Isolation Resistance | Riso | 5×10 ¹⁰ | 1×10 ¹¹ | — | Ω | DC500V 40 ~ 60% R.H. |
| | Floating Capacitance | Cf | — | 1 | 2.5 | pF | V=0, f=1MHz |
| | Response Time (Rise) | tr | — | 3 | 10 | μs | VCE=10V, IC=2mA |
| | Response Time (Fall) | tf | — | 3 | 10 | μs | RL=100Ω |

$$*CTR = \frac{I_C}{I_F} \times 100\%$$

Photocoupler 4N3X series

4.3 ISOLATION SPECIFICATION ACCORDING TO VDE

| Parameter | | Symbol | Conditions | Rating | Unit | Remark |
|---|-----------|---------------|--------------------------------|----------------------|------------|---------------------------|
| Class of environmental test | | - | DIN IEC68 | 55/100/21 | - | |
| Pollution | | - | DIN VDE0110 | 2 | - | |
| Maximum Operating Isolation Voltage | | V_{IORM} | - | 420 | V_{PEAK} | Refer to the Diagram 1, 2 |
| Partial Discharge Test Voltage (Between Input and Output) | Diagram 1 | V_{pr} | $t_p=60s, q_c<5pC$ | 630 | V_{PEAK} | |
| | Diagram 2 | | $t_p=1s, q_c<5pC$ | 788 | V_{PEAK} | |
| Maximum Over-Voltage | | $V_{INITIAL}$ | $t_{NI} = 10s$ | 6000 | V_{PEAK} | |
| Safety Maximum Ratings | | | | | | Refer to the Figure 1, 3 |
| 1) Case Temperature | | T_{si} | $I_F = 0, P_c = 0$ | 175 | °C | |
| 2) Input Current | | I_{si} | $P_c=0$ | 400 | mA | |
| 3) Electric Power (Output or Total Power Issipation) | | P_{si} | - | 700 | mW | |
| Isolation Resistance (Test Voltage Between Input and Output : DC500V) | | R_{ISO} | $T_a=T_{si}$ | MIN.10 ⁹ | Ω | |
| | | | $T_a=T_{opr}(MAX.)$ | MIN.10 ¹¹ | | |
| | | | $T_a=25\text{ }^\circ\text{C}$ | MIN.10 ¹² | | |

Precautions in performing isolation test

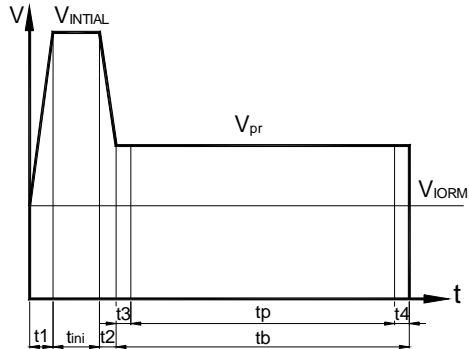
* Partial discharge test methods shall be the ones according to the specifications of DIN EN 60747-5-5

* Please don't carry out isolation test (V_{iso}) over $V_{INITIAL}$, This product deteriorates isolation characteristics by partial discharge due to applying high voltage (ex. $V_{INITIAL}$). And there is possibility that this product occurs partial discharge in operating isolation voltage (V_{IORM})

Photocoupler 4N3X series

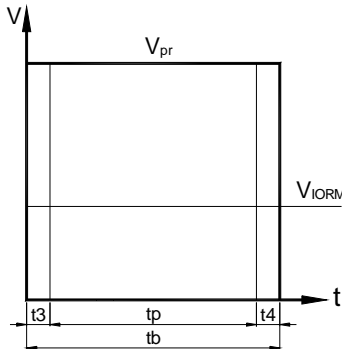
4.4 PARTIAL DISCHARGE TEST METHOD

Method (A) for type testing and random testing.



$t1, t2$ = 1 to 10s
 $t3, t4$ = 1s
 t_p (Partial Discharge Measuring Time) = 60s
 t_b = 62s
 t_{ini} = 10s

Method (B) for routine testing.



$t3, t4$ = 0.1s
 t_p (Partial Discharge Measuring Time) = 1s
 t_b = 1.2s

The partial discharge level shall not exceed 5 pc during the partial discharge measuring time interval t_p under the test conditions shown above.

Photocoupler 4N3X series

5. CHARACTERISTICS CURVES

Fig.1 Forward Current vs. Ambient Temperature

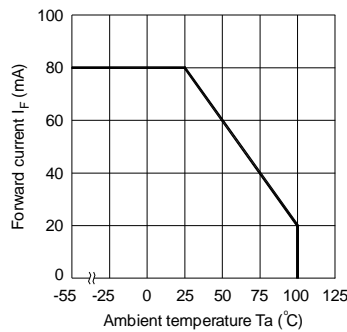


Fig.2 Collector Power Dissipation vs. Ambient Temperature

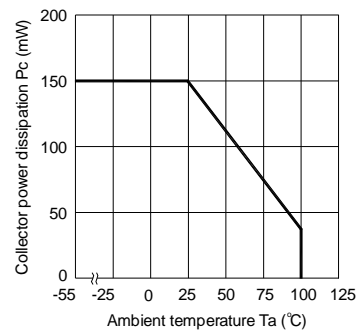


Fig.3 Forward Current vs. Forward Voltage

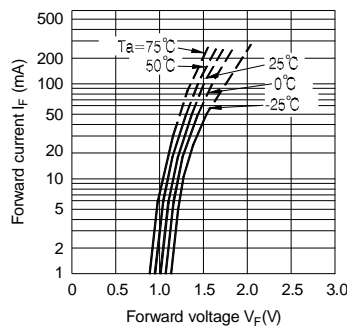


Fig.4 Current Transfer Ratio vs. Forward Current

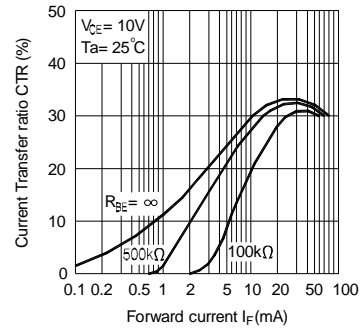


Fig.5 Collector Current vs. Collector-emitter Voltage

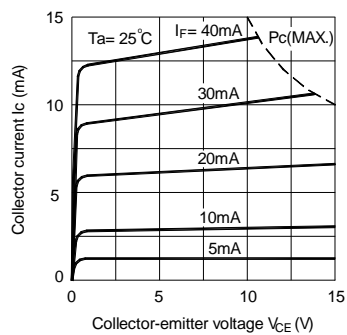
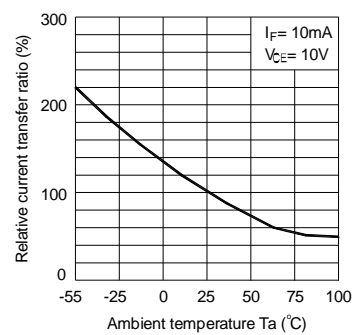


Fig.6 Relative Current Transfer Ratio vs. Ambient Temperature



Photocoupler 4N3X series

Fig.7 Collector-emitter Saturation Voltage vs. Ambient Temperature

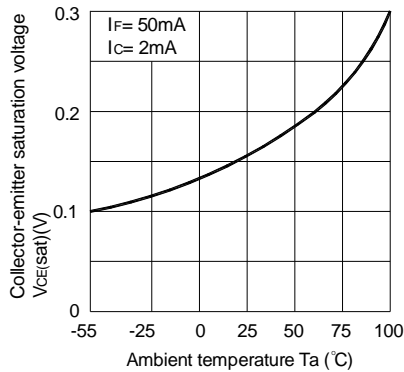


Fig.8 Collector Dark Current vs. Ambient Temperature

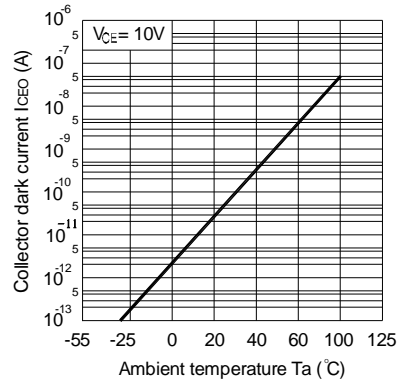


Fig.9 Response Time vs. Load Resistance

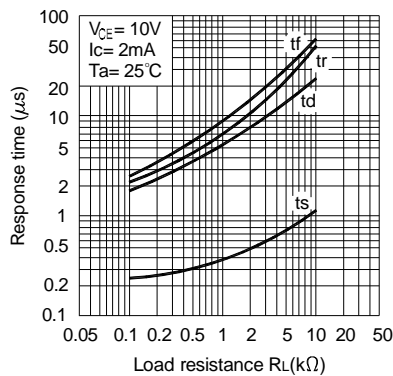


Fig.10 Frequency Response

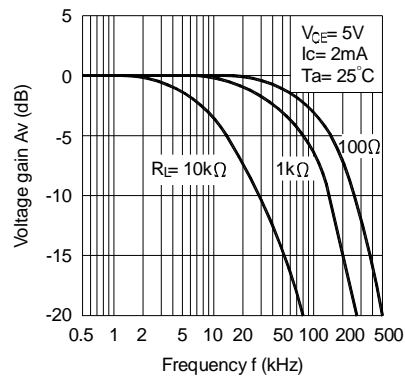
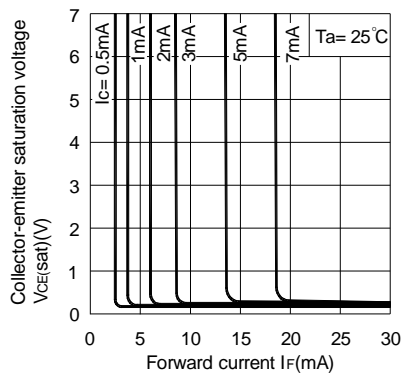
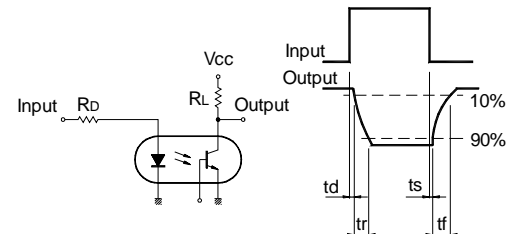


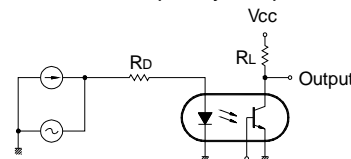
Fig.11 Collector-emitter Saturation Voltage vs. Forward Current



Test Circuit for Response Time



Test Circuit for Frequency Response



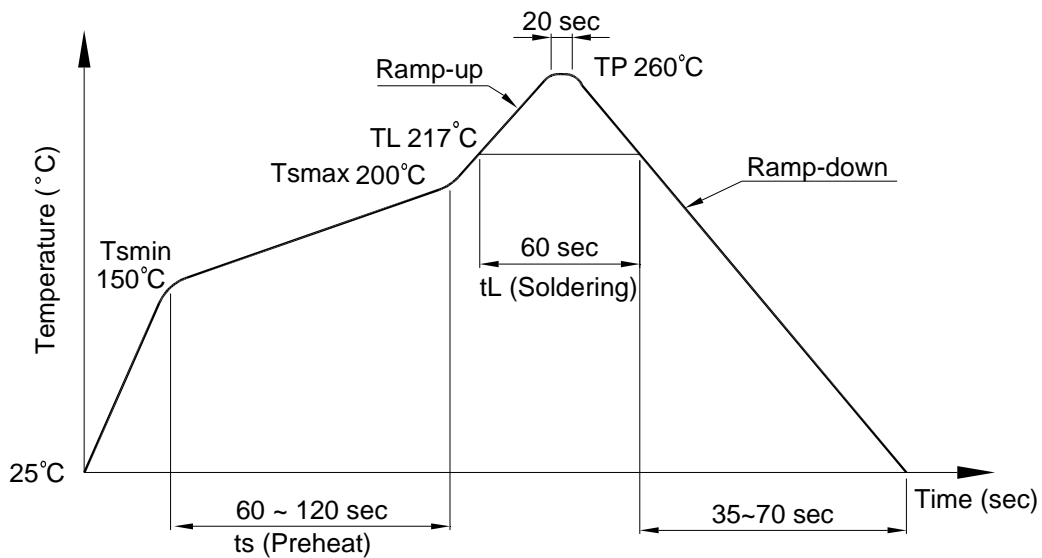
Photocoupler 4N3X series

6. TEMPERATURE PROFILE OF SOLDERING

6.1 IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

| Profile item | Conditions |
|----------------------------------|----------------|
| Preheat | |
| - Temperature Min (T_{Smin}) | 150°C |
| - Temperature Max (T_{Smax}) | 200°C |
| - Time (min to max) (t_s) | 90±30 sec |
| Soldering zone | |
| - Temperature (T_L) | 217°C |
| - Time (t_L) | 60 sec |
| Peak Temperature (T_P) | 260°C |
| Ramp-up rate | 3°C / sec max. |
| Ramp-down rate | 3~6°C / sec |



**Photocoupler
4N3X series**

6.2 Wave soldering (JEDEC22A111 compliant)

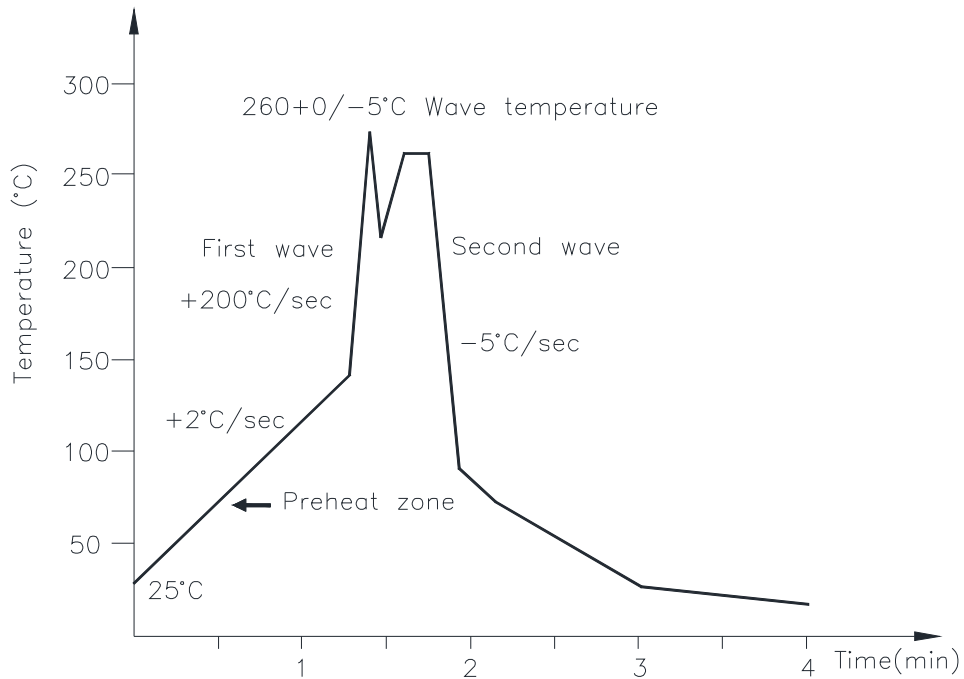
One time soldering is recommended within the condition of temperature.

Temperature: $260+0/-5^{\circ}\text{C}$

Time: 10 sec.

Preheat temperature: 25 to 140°C

Preheat time: 30 to 80 sec.



6.3 Hand soldering by soldering iron

Allow single lead soldering in every single process. One time soldering is recommended.

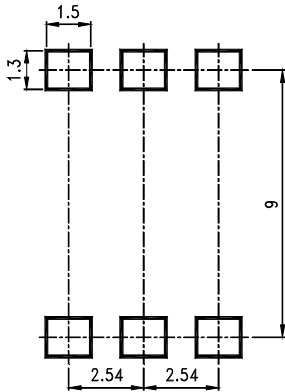
Temperature: $380+0/-5^{\circ}\text{C}$

Time: 3 sec max.

Photocoupler
4N3X series

7. RECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit: mm



**Photocoupler
4N3X series**

8. Naming rule

4N3X (1)-(2)

DEVICE PART NUMBER

- (1) No suffix = Dual-in-Line package
M = Wide lead spacing package
S = Surface mounting package

- (2) TAPING TYPE (TA,TA1 or none)
4N3X series have tape and reel solution.
Please refer to orientation of taping on Page P5

Example : 4N35S-TA1

4N3X(1)(2)-V

DEVICE PART NUMBER

- (1) No suffix = Dual-in-Line package
M = Wide lead spacing package
S = Surface mounting package

- (2) TAPING TYPE (TA,TA1 or none)
4N3X series have tape and reel solution.
Please refer to orientation of taping on Page P5

- (3) VDE order option

Example : 4N35STA1-V-G

9. Notes:

- LiteOn is continually improving the quality, reliability, function or design and LiteOn reserves the right to make changes without further notices.
- The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- When requiring a device for any "specific" application, please contact our sales in advice.
- If there are any questions about the contents of this publication, please contact us at your convenience.
- The contents described herein are subject to change without prior notice.
- Immerge unit's body in solder paste is not recommended.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

[Lite-On:](#)

[4N35S-TA1](#) [4N37S-TA](#) [4N35S-TA](#) [4N37S-TA1](#) [4N37M](#) [4N35M](#) [4N35](#) [4N37](#) [4N37S](#) [4N35S](#)



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.